TOSHIBA Bipolar Linear Integrated Circuit Silicon Monolithic

TA8127N,TA8127F

3V AM / FM 1chip Tuner IC

TA8127N and TA8127F are the AM / FM 1chip tuner ICs, which are designed for portable radios and 3V headphone radios.

Features

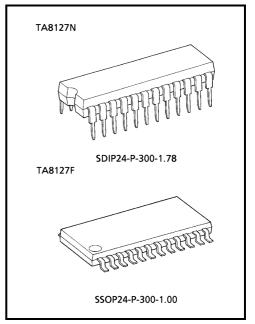
• Built-in

FM F / E, AM / FM IF and FM MPX

- AM detector coil and IF coupling condenser are not needed.
- Compact package

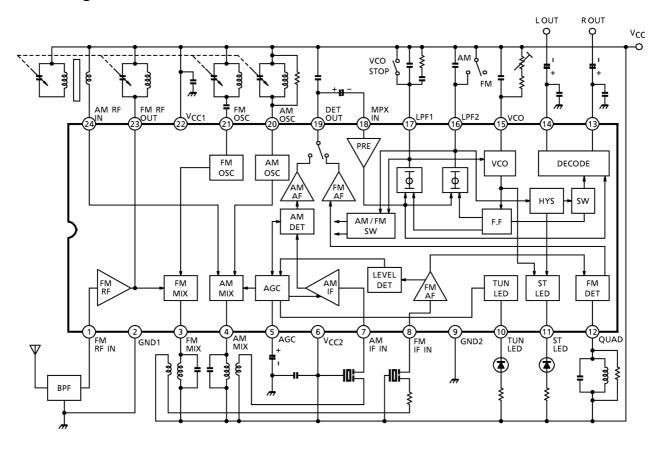
TA8127N: Shrink DIP 24 pin (1.78mm pitch) TA8127F: Mini flat packge 24 pin

• Operating supply voltage range $V_{CC} = 1.8{\sim}7.0V~(Ta=25{\circ}C)$



Weight SDIP24-P-300-1.78: 1.2g (typ.) SSOP24-P-300-1.00: 0.31 (typ.)

Block Diagram



Explanation Of Terminals

Pin No.	Item	Internal Circuit	DC Voltage (V) (at no Signal)		
			AM	FM	
1	FM-RF IN	FM-RF OUT (23) 1 C T Ldd GND1 (2)	0	0.7	
2	GND1 (GND for RF stage)	_	0	0	
3	FM MIX	Vcc1 22	3.0	3.0	
4	AM MIX	V _{CC1} 22 4 MIX MIX	3.0	3.0	
5	AGC (AM AGC)	FF AGC RF AGC GND2 9	0	0	
6	V _{CC2} (V _{CC} for IF / MPX stage)	_	3.0	3.0	
7	AM IF IN	V _{CC2} 6 G G G G G G G G G G G G G G G G G G	3.0	3.0	
8	FM IF IN	V _{CC2} 6 C C C C C C C C C C C C C C C C C C	3.0	3.0	

Pin No.	Item	Internal Circuit		tage (V) Signal)
1 11110.	icin	monal order	AM	FM
9	GND2 (GND for IF / MPX stage)	_	0	0
10	TUN LED (tuning LED)	VCC2 (6) (10) (10) (10) (10) (10) (10) (10) (10	ı	ı
11	ST LED (stereo LED)	76kHz 11) GND2 9	İ	_
12	QUAD (FM QUAD. Detector)	VCC2 (6)	3.0	3.0
13 14	R-OUT (R-ch output) L-OUT (L-ch output)	V _{CC2} 6 Cys	1.0	1.0
15	VCO	VCC2 6 DC AMP 15 GND2 9	2.5	2.5 (VCO stop mode)
16	LPF2 • LPF terminal for synchronous detector • Bias terminal for AM / FM SW circuit $V_{16} = V_{CC} \rightarrow AM (VCO \text{ stop})$ $V_{16} = OPEN \rightarrow FM$	GND2 9	3.0	2.2 (VCO stop mode 2.7)
17	LPF1 • LPF terminal for phase detector • VCO stop terminal V ₇ = V _{CC} →VCO stop	GND2 9	2.7	2.2

Pin No.	Item	Internal Circuit	DC Voltage (V) (at no Signal)		
1 11110.	item	memai oliodit	AM	FM	
18	MPX IN	(18 W W W W W W W W W W W W W W W W W W W	0.7	0.7	
19	DET OUT	VCC2 € AM FM B LOW→FM, HIGH→AM B LOW→AM, HIGH→FM	1.5	1.2	
20	AM OSC	VCC1 (2) MIX GND1 (2)	3.0	3.0	
21	FM OSC	VCC1 (22) (21) MIX — II —	3.0	3.0	
22	V _{CC1} (V _{CC} for RF stage)	_	3.0	3.0	
23	FM RF OUT	Cf. Pin(1)	3.0	3.0	
24	AM RF IN	V _{CC1} ② 49 GND1 ②	3.0	3.0	

Maximum Ratings (Ta = 25°C)

Characteris	stic	Symbol	Rating	Unit	
Supply voltage		V _{CC}	8	V	
LED current		I _{LED}	10	mA	
LED voltage		V_{LED}	8	V	
Power dissipation	TA8127N	P_{D}	1200	mW	
Fower dissipation	TA8127F	(Note)	400	11100	
Operating temperature		T _{opr}	-25~75	°C	
Storage temperature		T _{stg}	−55~150	°C	

Note: Derated above 25°C in the proportion of 9.6mW / °C for TA8127N and of 3.2mW / °C for TA8127F.

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Electrical Characteristics

Unless Otherwise Specified, $Ta = 25^{\circ}C$, $V_{CC} = 3V$, F / E: f = 83MHz, $f_{m} = 1kHz$ $FM \ IF$: f = 10.7MHz, $\Delta f = \pm 22.5kHz$, $f_{m} = 1kHz$ ΔM : f = 1MHz, ΔM ΔM : ΔM

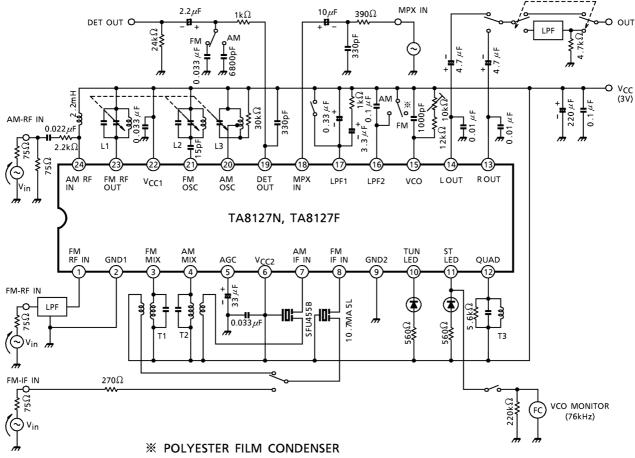
Characteristic		Symbol	Test Cir– cuit	Test Condition	Min.	Тур.	Max.	Unit	
Sunni	y current	I _{CC (FM)}		V _{in} = 0, FM mode	_	13.2	20.0	mA	
Биррі	y current	I _{CC (AM)}	1	V _{in} = 0, AM mode	_	8.4	13.5	111/4	
F/E	Input limiting voltage	V _{in (lim.)}	1	– 3dB limiting	_	10.0	_	dBµV EMF	
	Local OSC voltage	Vosc	2	f _{OSC} = 72.3MHz	_	105	_	mV _{rms}	
	Input limiting voltage	V _{in (lim.)} IF	1	– 3dB limiting	40	46	53	dBµV EMF	
	Rcovered output voltage	covered output voltage V _{OD}		V _{in} = 80dBµV EMF	55	80	110	mV _{rms}	
FM IF	Signal to noise ratio	S/N	1	V _{in} = 80dBµV EMF	_	70	_	dB	
''	Total harmonic distortion	THD	1	V _{in} = 80dBµV EMF	_	0.4	_	%	
	AM rejection ratio	AMR		V _{in} = 80dBμV EMF	_	32	_	dB	
	Lamp on sensitivity	V_{L}	1	I _L = 1mA	45	51	56	dBµV EMF	
	Gain	G _V	1	V _{in} = 26dBµV EMF	40	70	110	.,	
	Recovered output voltage	V _{OD}	1	V _{in} = 60dBµV EMF	55	80	110	mV _{rms}	
AM	Signal to noise ratio	S/N	1	V _{in} = 60dBµV EMF	_	42	_	dB	
	Total harmonic distortion	THD	1	V _{in} = 60dBµV EMF	_	1.0	_	%	
	Lamp on sensitivity	VL	1	I _L = 1mA	20	25	30	dBµV EMF	
Pin(19) output resistance			1	FM mode	_	0.75	_	kΩ	
FIII(18	o output resistance	R ₁₉		AM mode	_	12.5		K77	

Characteristic			Symbol	Test Cir– cuit	Test Condition		Min.	Тур.	Max.	Unit	
	Input resistan	се	R _{IN}	_	-	_		24	_	kO	
	Output resista	ınce	R _{OUT}	_	-	_	_	5	_	kΩ	
	Max. Compos signal input vo		V _{in (max.)} stereo	1	L+R = 90%, P = 10% f _m = 1kHz, THD = 3%		_	350	_	mV _{rms}	
					L+R =	f _m = 100Hz	_	42	_		
	Separation		Sep	1	135mV _{rms}	f _m = 1kHz 35 42 —	_	dB			
					P = 15mV _{rms}	f _m = 10kHz	_	42			
	Total harmonic distortion	Monaural	THD (monaural)	1	V _{in} = 150mV _{rms}		_	0.2	_	%	
MPX		Stereo	THD (stereo)	1	L+R = $135\text{mV}_{\text{rms}}$, P = 15mV_{rms}		_	0.2	_		
	Voltage gain		G _{V (MPX)}	1	V _{in} = 150mV _{rms}		-5	-3	-1	dB	
	Channel balar	nce	C. B.	1	V _{in} = 150mV _{rm}	S	-2	0	2	uв	
	Stereo lamp	On	V _{L (ON)}	1	Pilot input		_	8	16	mV _{rms}	
	sensitivity	Off	V _{L (OFF)}		Pilot input	Pilot input		6	_	III v rms	
	Stereo lamp hysteresis		V _H	1	To LED turn of LED turn on	f from	_	2	_	${\rm mV}_{\rm rms}$	
	Caputure range		C. R.	1	P = 15mV _{rms}		_	±3	_	%	
	Signal to nois	e ratio	S/N	1	V _{in} = 150mV _{rm}	S	_	70	_	dB	

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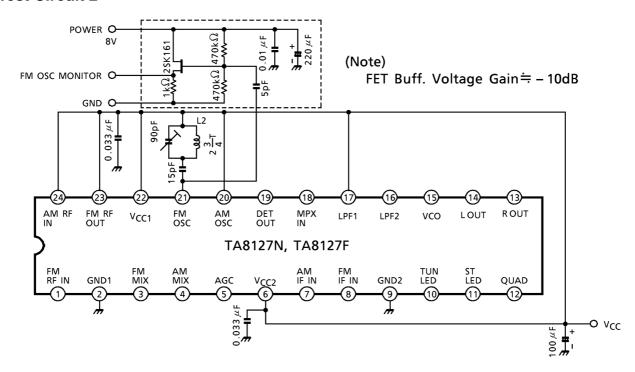
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Test Circuit 1



Using other types of condensers, there are some cases that the MPX does not do normal stereo action at high temperature or low temperature.

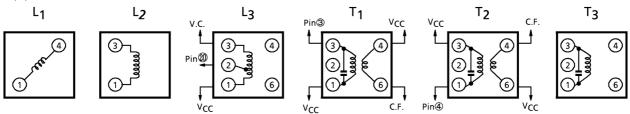
Test Circuit 2



Coil Data

Coil No.	Test	L	Co	0-			Turns			Wire	Reference	
COII NO.	Freq. (Hz)	(µH)	(pF)	QO	1–2	2–3	1–3	1–4	4–6	(mmφ)		
L ₁ FM RF	100M	_	ı	100	_	_	_	$2\frac{1}{2}$	_	0.5UEW	(S) 53T-037-202	
L ₂ FM OSC	100M	_	1	100	_	_	$2\frac{3}{4}$	_	_	0.5UEW	(S) 0258-244	
L ₃ AM OSC	796k	288	_	115	13	73	_	_	_	0.08UEW	(S) 4147-1356-038	
T ₁ FM MIX	10.7M	_	75	100	_	_	13	_	2	0.1UEW	(S) 2153-414-041	
T ₂ AM MIX	455k	_	180	120	_	_	180	_	15	0.08UEW	(S) 2150-2162-165	
T ₃ FM DET	10.7M	_	47	165	_	_	16	_	_	0.09UEW	(S) 2153-4095-122	

(S): SUMIDA electric CO., LTD

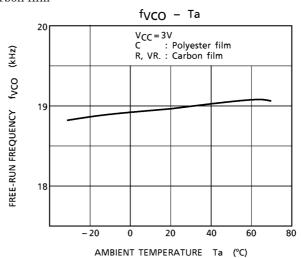


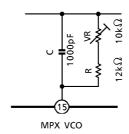
Hint On Use Of TA8127N And TA8127F

External parts of MPX VCO

(1) Temperature characteristic of MPX VCO free –run frequency. The temperature characteristic of MPX VCO is shown in the diagram as below. Select one with a better temperature characteristic (C, R and VR.) in use. We recommend,

C : Polyester film R, VR: Carbon film





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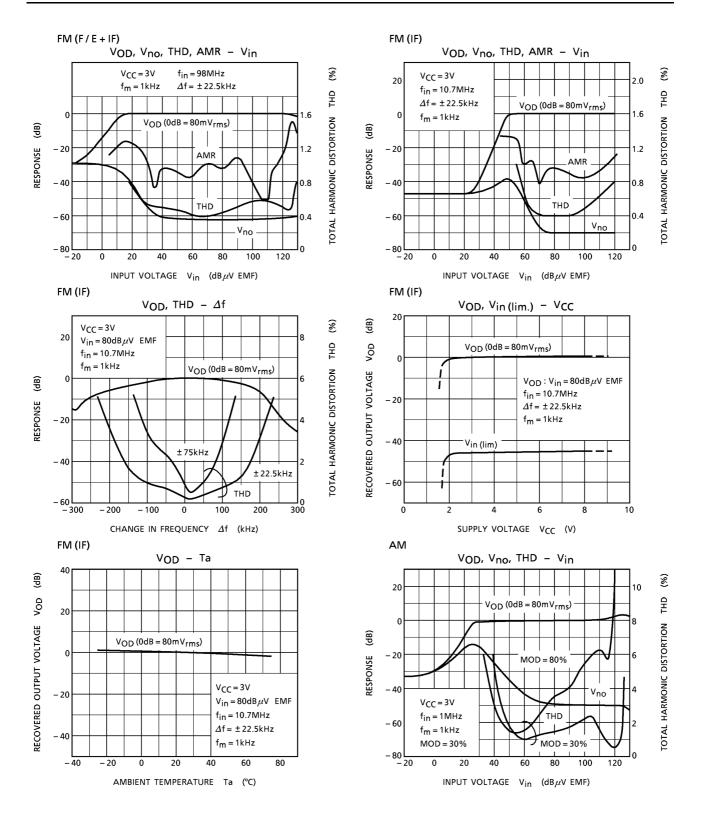
(2) Value of the external parts

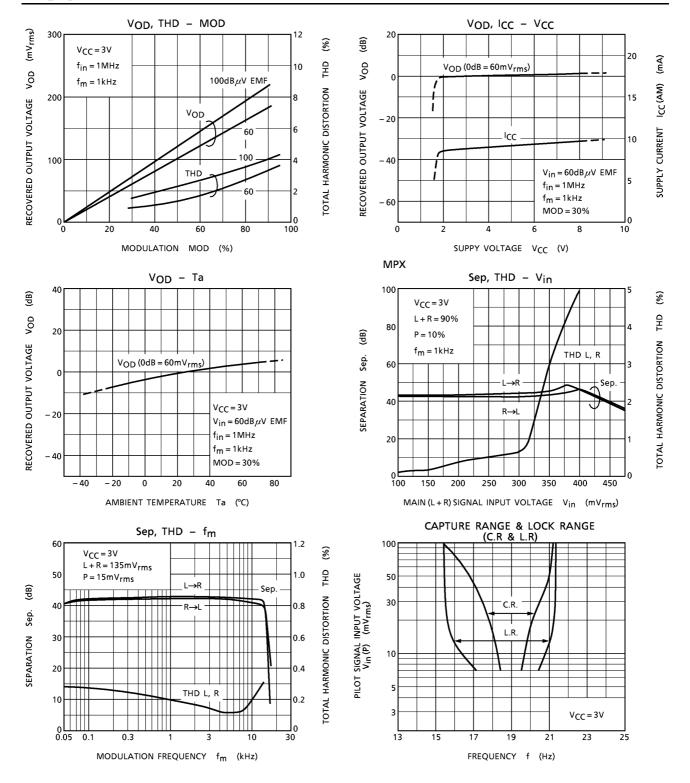
We recommend to set up these value as below.

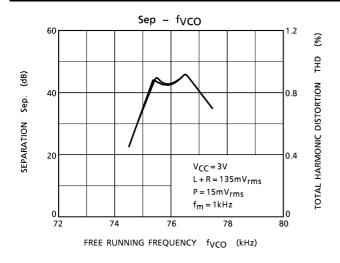
 $\mathrm{R}=12\mathrm{k}\Omega$

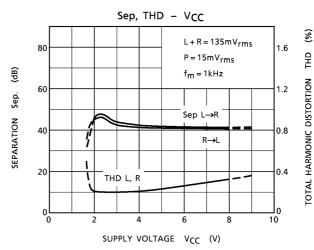
 $VR = 10k\Omega$

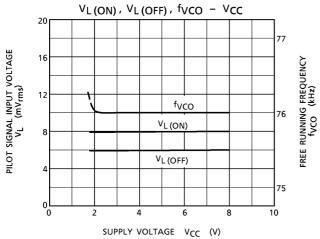
C = 1000pF







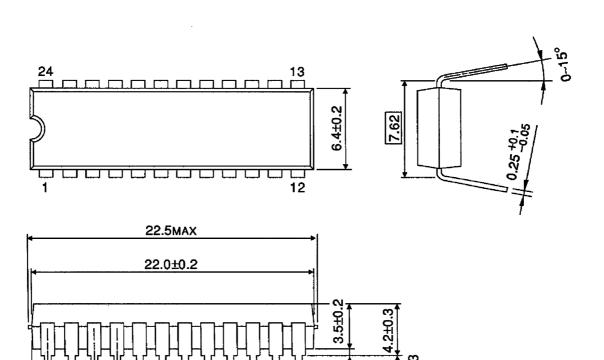




Unit: mm

Package Dimensions

SDIP24-P-300-1.78



0.46±0.1 0.18 M

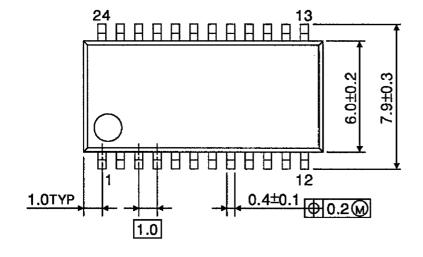
Weight: 1.2g (typ.)

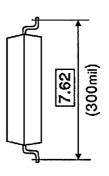
1.778

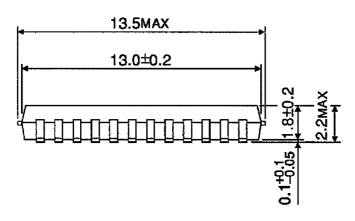
1.221TYP

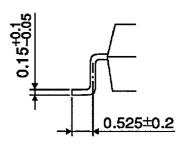
Package Dimensions

SSOP24-P-300-1.00 Unit: mm









Weight: 0.31g (typ.)

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